

ORDERING INFORMATION

Device	Temperature Range	Package
MC1454G	0°C to +70°C	Metal Can
MC1554G	-55°C to +125°C	Metal Can

MC1454G
MC1554G

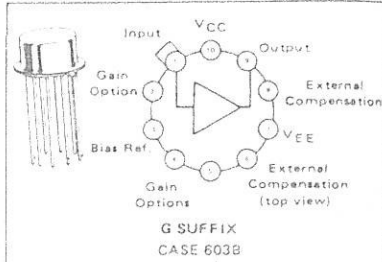
1-WATT POWER AMPLIFIERS

... designed to amplify signals to 300-kHz with 1-Watt delivered to a direct coupled or capacitively coupled load.

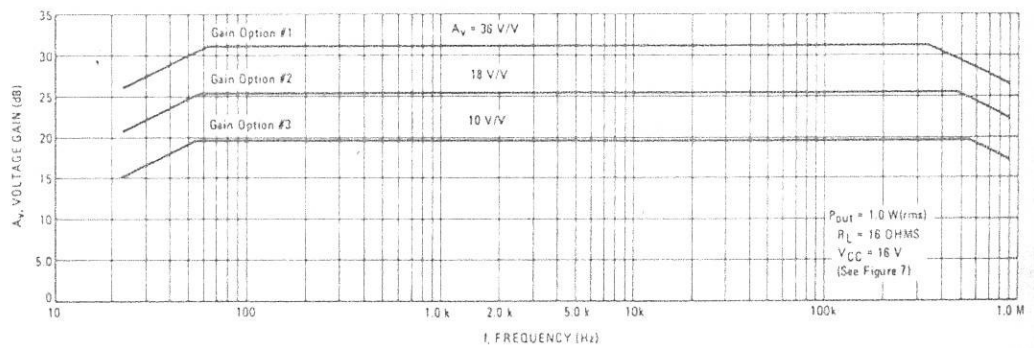
- Low Total Harmonic Distortion -- 0.4% (Typ) @ 1 Watt
- Low Output Impedance -- 0.2 Ohm
- Excellent Gain -- Temperature Stability

1-WATT
POWER AMPLIFIER
INTEGRATED CIRCUIT

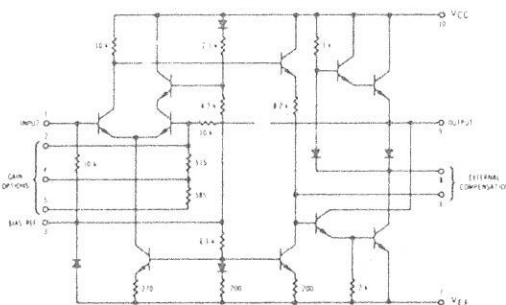
SILICON MONOLITHIC
EPITAXIAL PASSIVATED



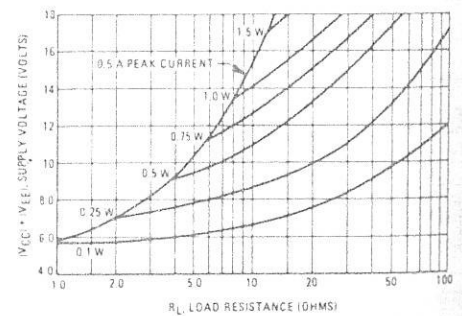
VOLTAGE GAIN versus FREQUENCY ($R_L = 16 \text{ OHMS}$)



CIRCUIT SCHEMATIC



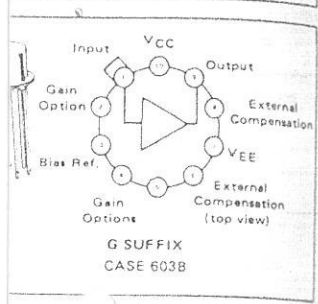
MAXIMUM AVAILABLE OUTPUT POWER
(SINE WAVE)



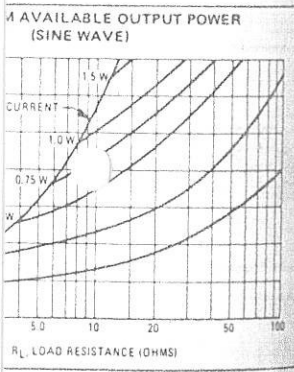
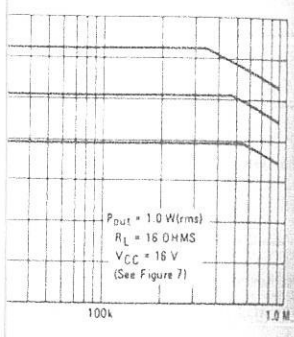
MC1454G
MC1554G

1-WATT
POWER AMPLIFIER
INTEGRATED CIRCUIT

SILICON MONOLITHIC
EPITAXIAL PASSIVATED



G SUFFIX
CASE 603B



ELECTRICAL CHARACTERISTICS (T_C = +25°C unless otherwise noted)
Frequency compensation shown in Figures 6 and 7.

Characteristic	Figure	R _L (Ohms)	Gain Option*	Symbol	MC1554 (-55 to +125°C)			MC1454 (0 to +70°C)			Unit
					Min	Typ	Max	Min	Typ	Max	
Output Power (for e _{out} < 5.0% THD)	1	16	—	P _{out}	1.0	1.1	—	—	1.0	—	Watt
Power Dissipation (@ P _{out} = 1.0 W)	1	16	—	P _D	—	0.9	1.2	—	0.9	—	Watt
Voltage Gain	1	16 16 16	10 18 36	A _v	8.0	10	12	—	10	—	V/V
Input Impedance	1	—	10	z _{in}	7.0	10	—	3.0	10	—	kΩ
Output Impedance	1	—	10	z _o	—	0.2	—	—	0.4	—	Ω
Power Bandwidth (for e _{out} < 5.0% THD)	2	16 16 16	10 18 36	BW	—	270	—	—	270	—	kHz
Total Harmonic Distortion (for e _{in} < 0.05% THD, f = 20 Hz to 20 kHz)	2			THD							%
P _{out} = 1.0 Watt (sinewave)		16	10		—	0.4	—	—	0.4	—	
P _{out} = 0.1 Watt (sinewave)		16	10		—	0.5	—	—	0.5	—	
Zero Signal Current Drain	3	∞	—	I _D	—	11	15	—	11	20	mAdc
Output Noise Voltage	3	16	10	V _n	—	0.3	—	—	0.3	—	mVrms
Output Quiescent Voltage (Split Supply Operation)	4	16	—	V _O (dc)	—	±10	±30	—	±10	—	mVdc
Positive Supply Sensitivity (V _{EE} constant)	5	∞	—	S ⁺	—	-40	—	—	-40	—	mV/V
Negative Supply Sensitivity (V _{CC} constant)	5	∞	—	S ⁻	—	-40	—	—	-40	—	mV/V

* To obtain the voltage gain characteristic desired, use the following pin connections: Voltage Gain

Pin Connection
 10 Pins 2 and 4 open, Pin 5 to ac ground
 18 Pins 2 and 5 open, Pin 4 to ac ground
 36 Pin 2 connected to Pin 5, Pin 4 to ac ground

Characteristic Definitions
(Linear Operation)

FIGURE 1

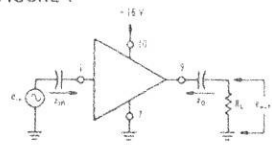


FIGURE 3

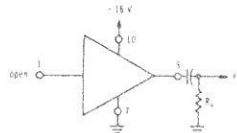


FIGURE 4

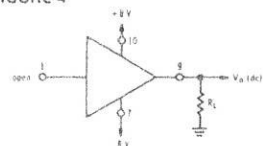


FIGURE 2

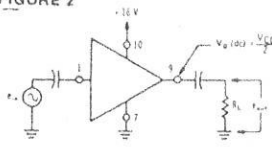
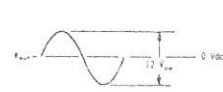
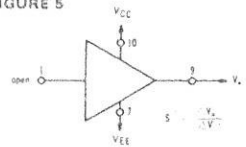


FIGURE 5



MAXIMUM RATINGS (T_C = +25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Total Power Supply Voltage	$ V_{CC} + V_{EE} $	18	Vdc
Peak Load Current	I_{out}	0.5	Ampere
Audio Output Power	P_{out}	1.8	Watts
Power Dissipation (package limitation)			
T _A = +25°C	P_D	600	mW
Derate above 25°C	$1/\theta_{JA}$	4.8	mW/°C
T _C = +25°C	P_D	1.8	Watts
Derate above 25°C	$1/\theta_{JC}$	14.4	mW/°C
Operating Temperature Range	MC1454 MC1554	T _A	0 to +70 -55 to +125
Storage Temperature Range		T _{stg}	-55 to +150

TYPICAL CONNECTIONS

FIGURE 6 – SPLIT SUPPLY OPERATION VOLTAGE
GAIN (A_V) = 10, f_{LOW} ≈ 25 Hz

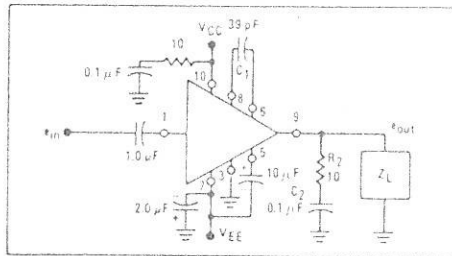
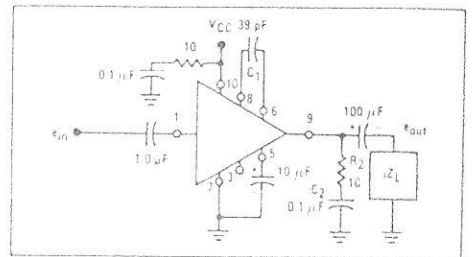


FIGURE 7 – SINGLE SUPPLY OPERATION VOLTAGE
GAIN (A_V) = 10, f_{LOW} ≈ 100 Hz



RECOMMENDED OPERATING CONDITIONS

In order to avoid local VHF instability, the following set of rules must be adhered to:

1. An R-C stabilizing network (0.1 μF in series with 10 ohms) should be placed directly from pin 9 to ground, as shown in Figures 6 and 7, using short leads, to eliminate local VHF instability caused by lead inductance to the load.
2. Excessive lead inductance from the V_{CC} supply to pin 10 can cause high frequency instability. To prevent this, the V_{CC} by pass capacitor should be connected with short leads from the V_{CC} pin to ground. If this capacitor is remotely located a series R-C network (0.1 μF and 10 ohms) should be used directly from pin 10 to ground as shown in Figures 6 and 7.

3. Lead lengths from the external components to pins 7, 9, and 10 of the package should be as short as possible to insure good VHF grounding for these points.

Due to the large bandwidth of the amplifier, coupling must be avoided between the output and input leads. This can be assured by either (a) use of short leads which are well isolated, (b) narrow banding the overall amplifier by placing a capacitor from pin 1 to ground to form a low pass filter in combination with the source impedance, or (c) use of a shielded input cable. In applications which require upper band edge control the input low pass filter is recommended.

TYPICAL CHARACTERISTICS

FIGURE 8 – TOTAL HARMONIC DISTORTION
versus LOAD RESISTANCE

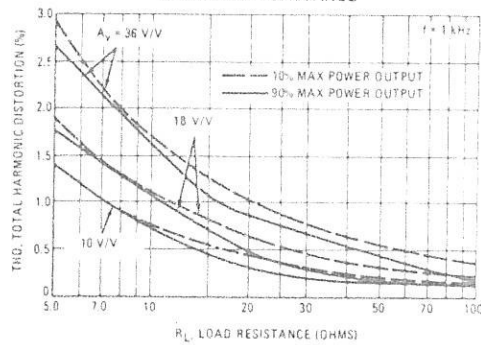
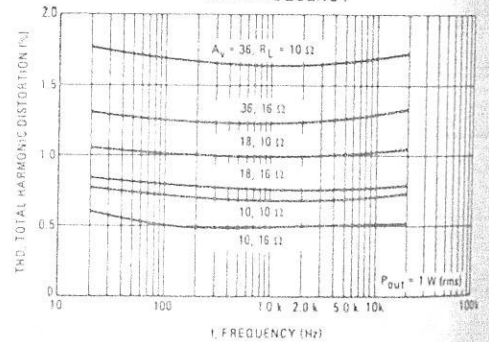


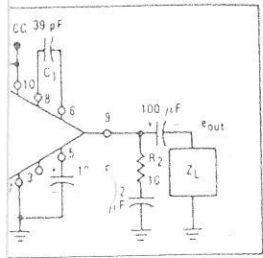
FIGURE 9 – TOTAL HARMONIC DISTORTION
versus FREQUENCY



TYPICAL CHARACTERISTICS (continued)

Pin	Unit
3	Vdc
5	Ampere
8	Watts
10	mW
18	mW/°C
18	Watts
14	mW/°C
70	°C
125	°C
150	°C

APPLY OPERATION VOLTAGE
 $f = 10$, $f_{LOW} \approx 100$ Hz



terminal components to pins 7, 9, and 10 of the device as possible to insure good VHF grounding.

In the amplifier, coupling must be avoided between the input and output leads. This can be assured by either (a) use of shielded cables, (b) narrow banding the overall amplifier, or (c) use of a shielded input cable. In per band edge control the input low pass filter.

TOTAL HARMONIC DISTORTION
 versus FREQUENCY

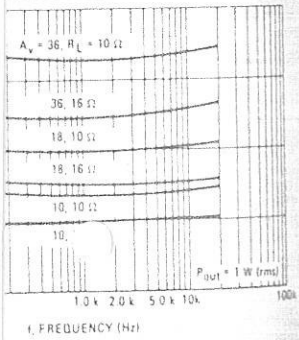


FIGURE 10 – VOLTAGE GAIN versus TEMPERATURE

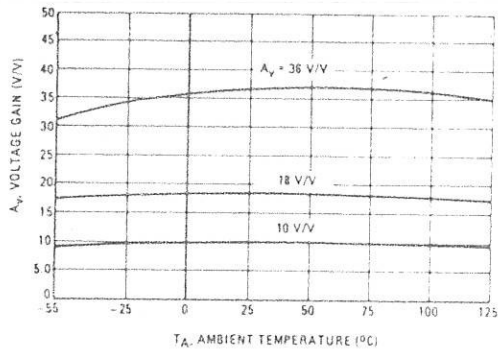


FIGURE 11 – OUTPUT VOLTAGE CHANGE

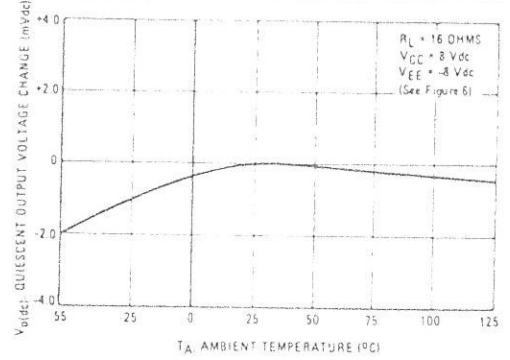


FIGURE 12 – VOLTAGE GAIN versus FREQUENCY ($R_L = \infty$)

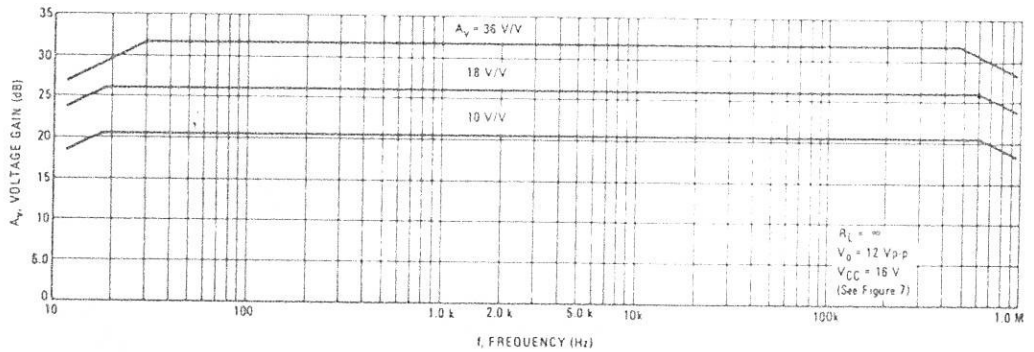


FIGURE 13 – MAXIMUM DEVICE DISSIPATION
 (SINE WAVE)

